

# BRCS080C03SC

Rev.A Aug.-2023

## / Descriptions

SOP-8

Complementary Enhancement MOSFET in a SOP-8 Plastic Package.

## / Features

N-channel

$V_{DS}(V)=30V$   $I_D=15.5A$

$R_{DS(ON)}@10V<8m$  (Typ.7.5mR)

$R_{DS(ON)}@4.5V<15m$  (Typ.11mR)

HF Product.

P-channel

$V_{DS}(V)=-30V$   $I_D=-11.5A$

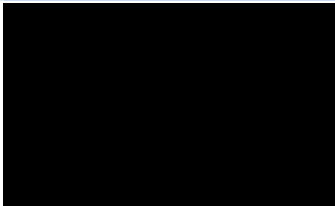
$R_{DS(ON)}@-10V<13m$  (Typ.12mR)

$R_{DS(ON)}@-4.5V<20m$  (Typ.17mR )

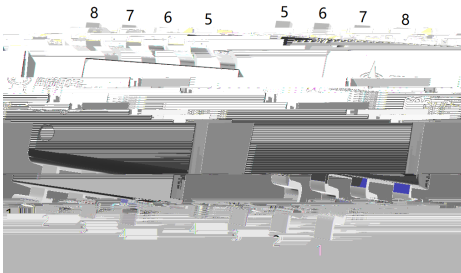
## / Applications

Battery protection switch, Mobile device battery charging and discharging, Load switch.

## / Equivalent Circuit



## / Pinning



PIN1 S1 PIN 2 G1 PIN 3 S2 PIN 4 G2

PIN 5 D2 PIN 6 D2 PIN 7 D1 PIN 8 D1

## / Marking

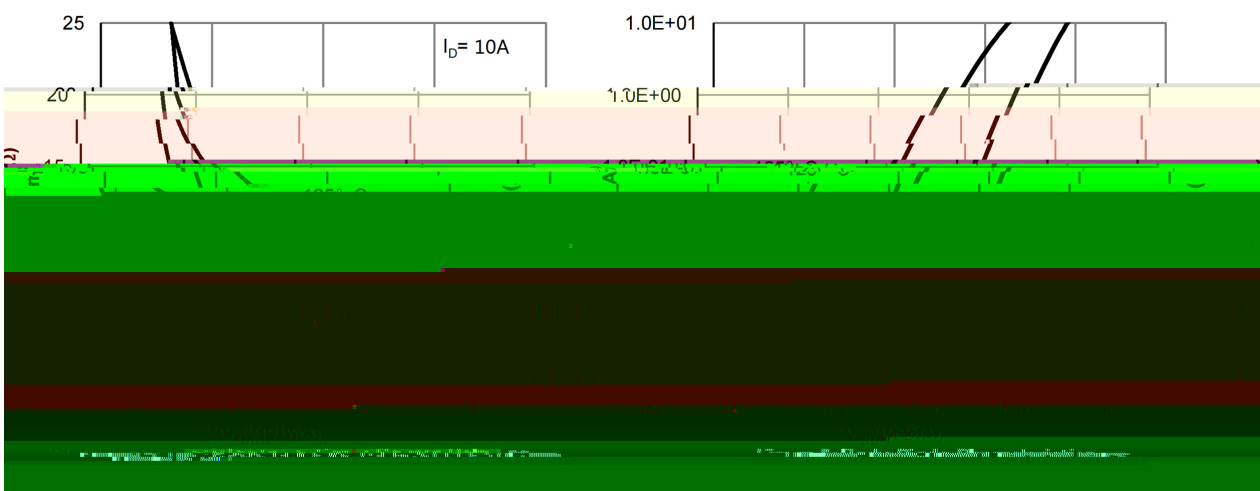
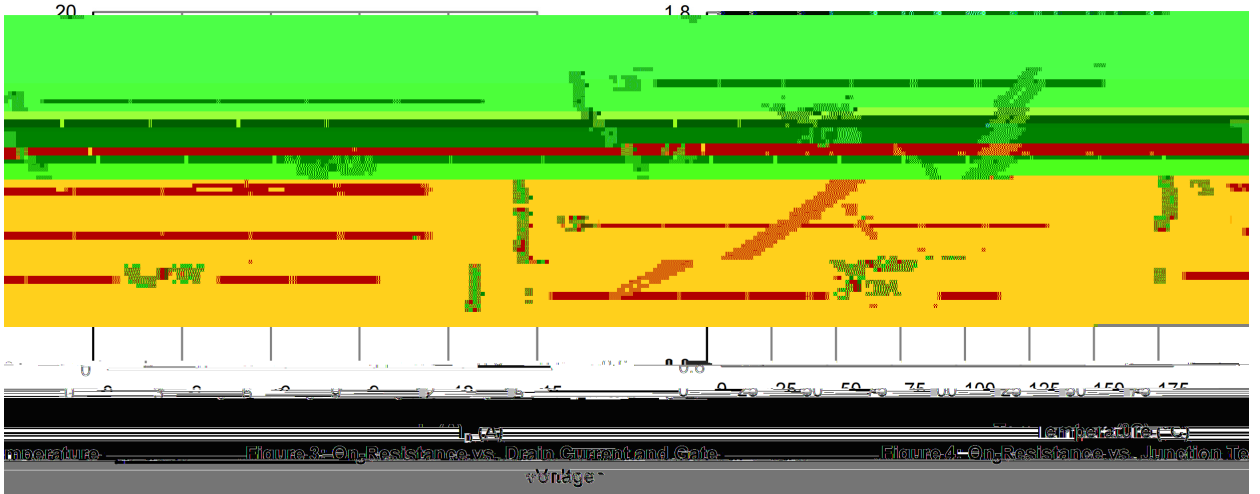
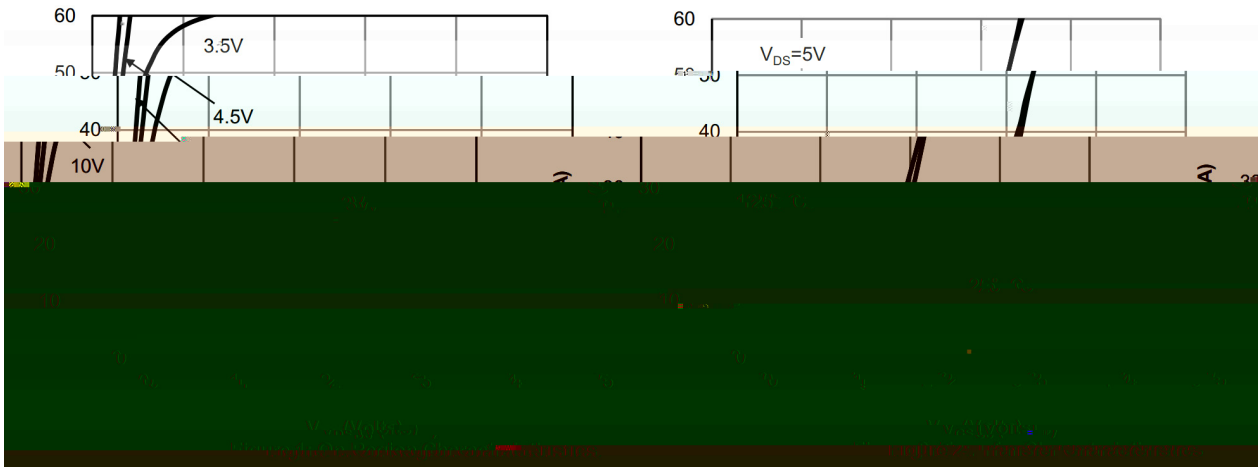
See Marking Instructions.

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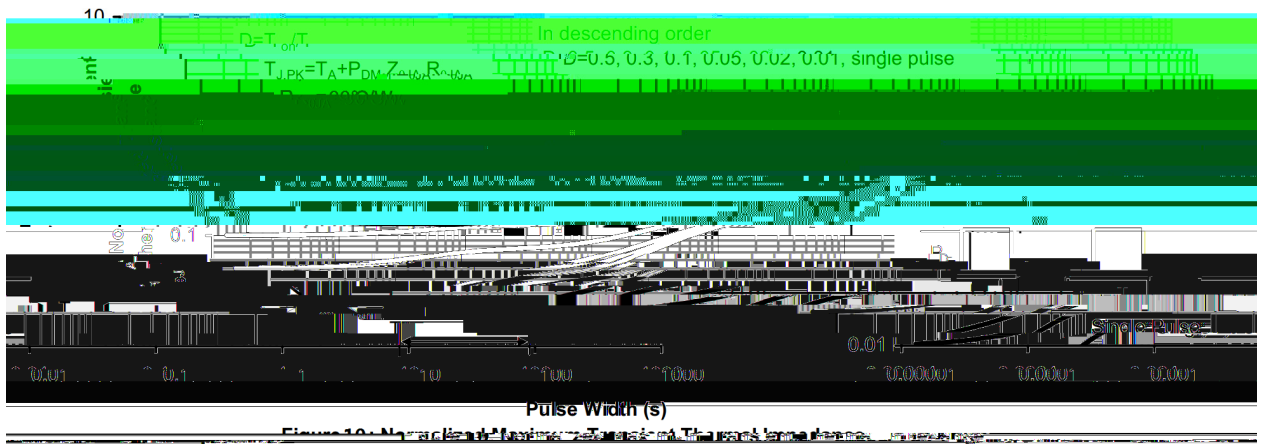
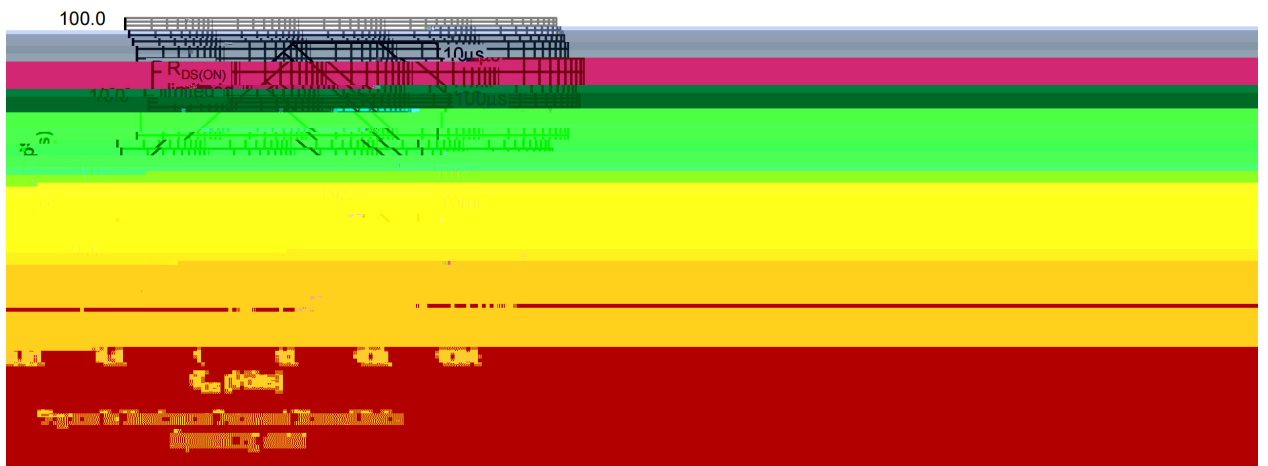
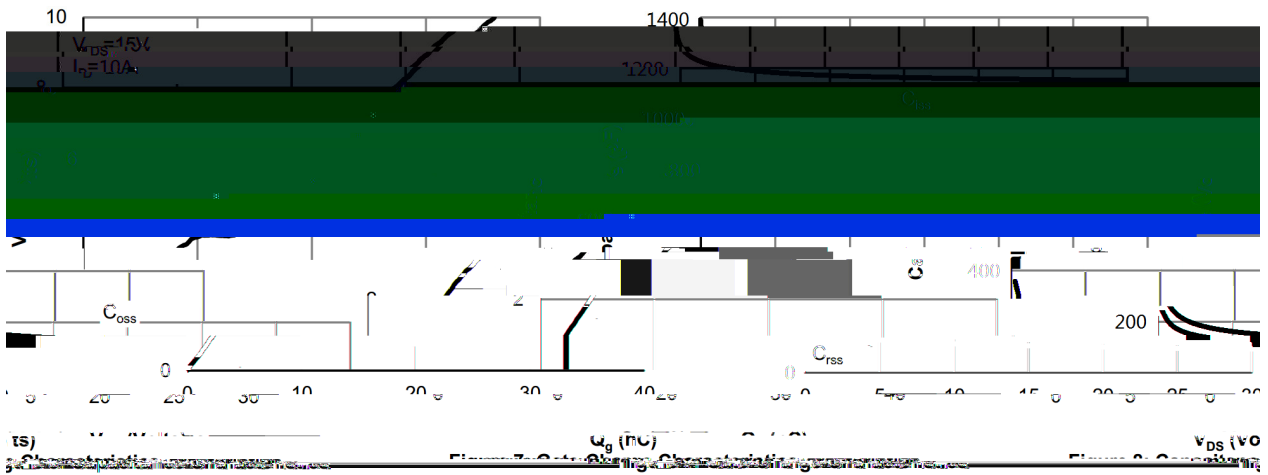
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**N- / N-CHANNEL Electrical Characteristic Curve**



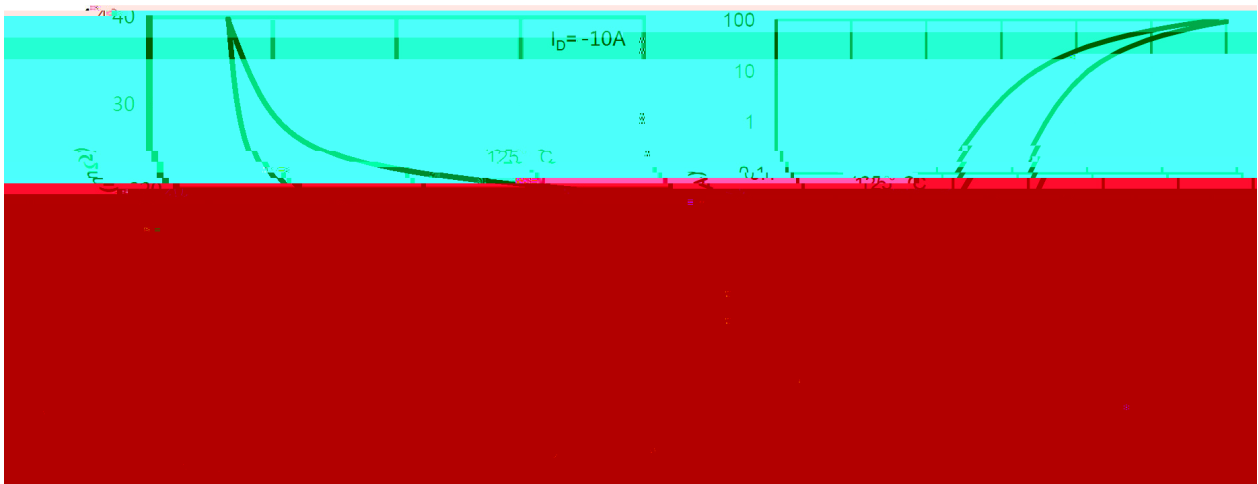
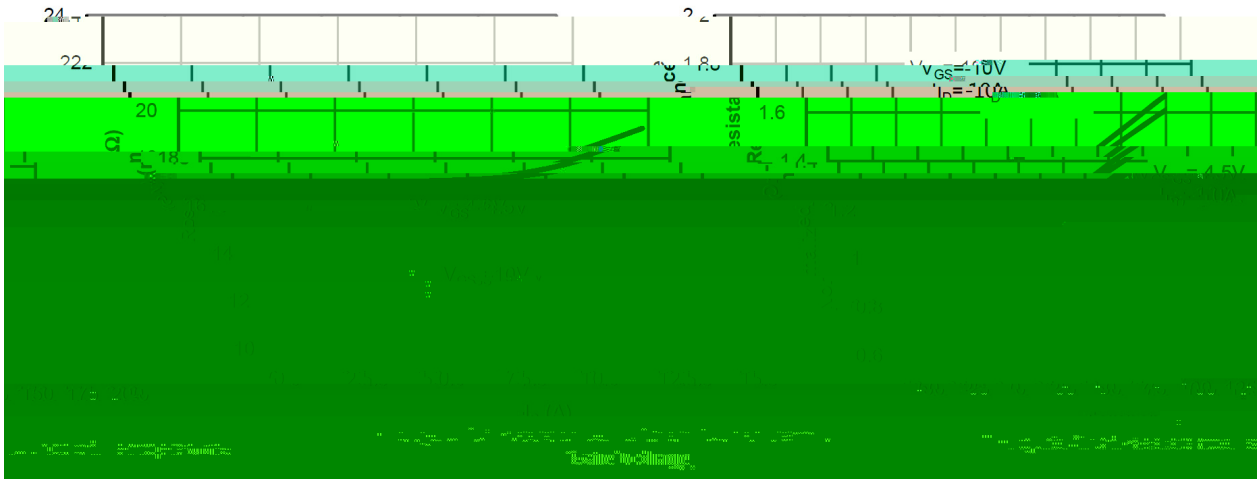
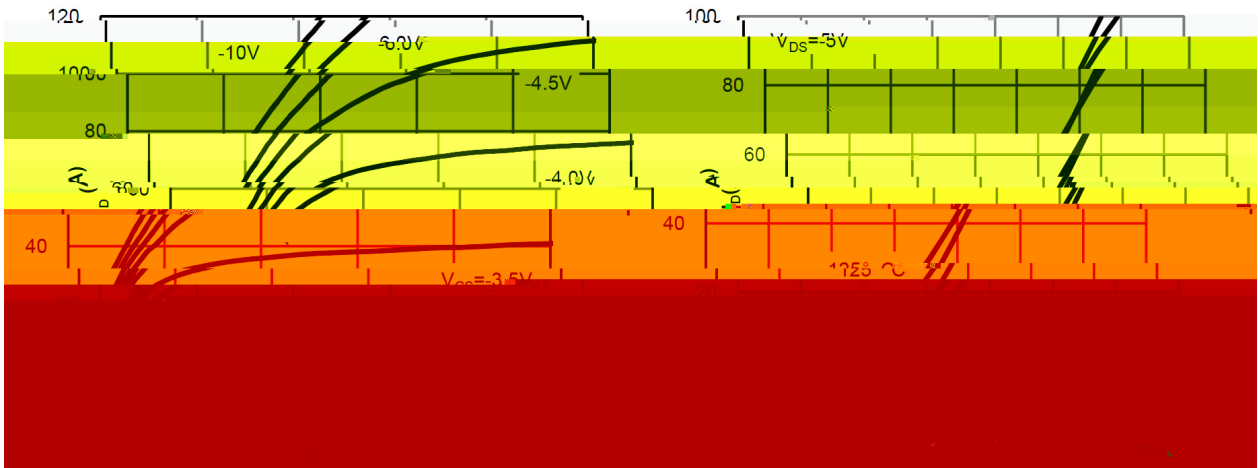
**N- / N-CHANNEL Electrical Characteristic Curve**



**P- /P-CHANNEL Electrical Characteristics(Ta=25 )**

| Parameter                         | Symbol               | Test Conditions   | Min  | Typ  | Max  | Unit |
|-----------------------------------|----------------------|---|------|------|------|------|
| Drain-Source Breakdown Voltage    | BV <sub>DSS</sub>    | V <sub>GS</sub> =0V I <sub>D</sub> =-250μA  | -30  |      |      | V    |
| Zero Gate Voltage Drain Current   | I <sub>DSS</sub>     | V <sub>DS</sub> =-4030V <sub>GS</sub> =0V   |      |      | -1.0 | μA   |
| Gate-Body leakage current         | I <sub>GSS</sub>     | V <sub>GS</sub> =±20V V <sub>DS</sub> =0V   |      |      | ±100 | nA   |
| Gate Threshold Voltage            | V <sub>GS(th)</sub>  | V <sub>DS</sub> =V <sub>GS</sub> I <sub>D</sub> =-250μA                               | -1.0 | -1.5 | -2.5 | V    |
| Static Drain-Source On-Resistance | R <sub>DS(on)</sub>  | V <sub>GS</sub> =-10V I <sub>D</sub> =-10A  |      | 12   | 13   | m    |
|                                   |                      | V <sub>GS</sub> =-4.5V I <sub>D</sub> =-10A   |      | 17   | 20   | m    |
| Diode Forward Voltage             | V <sub>SD</sub>      | V <sub>GS</sub> =0V I <sub>S</sub> =-1.0A   |      |      | -1.4 | V    |
| Input Capacitance                 | C <sub>iss</sub>     | V <sub>DS</sub> =-25V V <sub>GS</sub> =0V<br>f=1.0MHz                                 |      | 2100 |      | pF   |
| Output Capacitance                | C <sub>oss</sub>     |   |      | 1900 |      | pF   |
| Reverse Transfer Capacitance      | C <sub>rss</sub>     |   |      | 640  |      | pF   |
| Gate resistance                   | R <sub>g</sub>       | V <sub>DS</sub> =0V V <sub>GS</sub> =0V<br>f=1.0MHz                                   |      | 4    |      |      |
| Total Gate Charge                 | Q <sub>g(10V)</sub>  | V <sub>GS</sub> =-10V V <sub>DS</sub> =-15V<br>I <sub>D</sub> =-10A                   |      | 35   |      | nC   |
| Total Gate Charge                 | Q <sub>g(4.5V)</sub> |   |      | 17   |      | nC   |
| Gate-Source Charge                | Q <sub>gs</sub>      |   |      | 5.7  |      | nC   |
| Gate-Drain Charge                 | Q <sub>gd</sub>      |   |      | 8.8  |      | nC   |
| Turn-On Delay Time                | t <sub>d(on)</sub>   | V <sub>DS</sub> =-15 V V <sub>GS</sub> =-10V<br>R <sub>L</sub> =1 R <sub>GEN</sub> =3 |      | 11   |      | ns   |
| Turn-On Rise Time                 | t <sub>r</sub>       |   |      | 7.5  |      | ns   |
| Turn-Off Delay Time               | t <sub>d(off)</sub>  |   |      | 43.5 |      | ns   |
| Turn-Off Fall Time                | t <sub>f</sub>       |   |      | 17.5 |      | ns   |

**P- / P-CHANNEL Electrical Characteristic Curve**



**P- / P-CHANNEL Electrical Characteristic Curve**

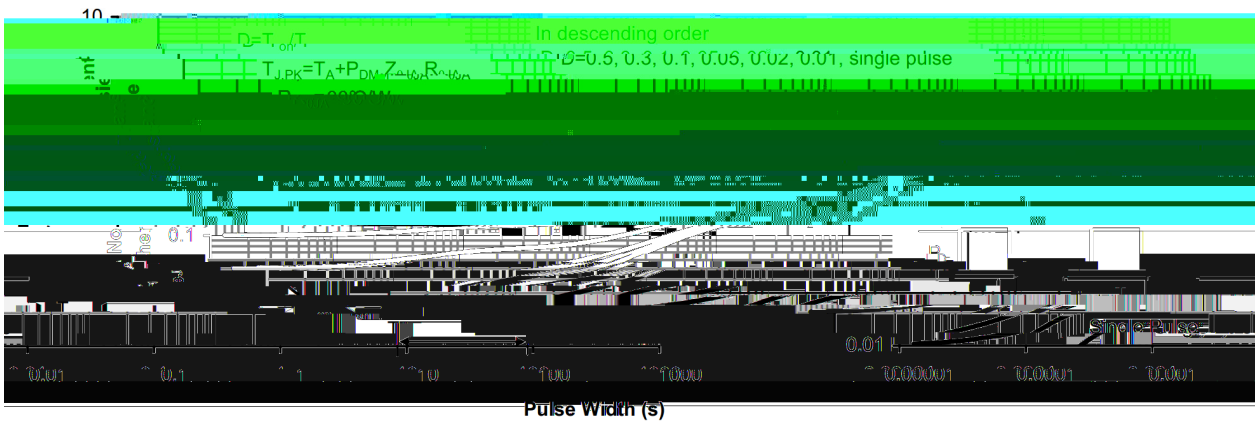
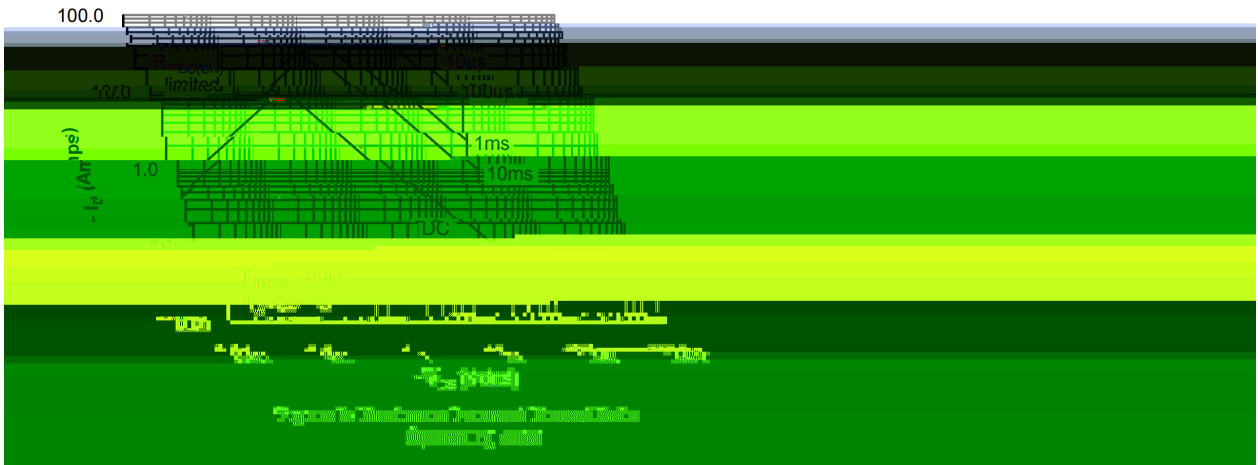
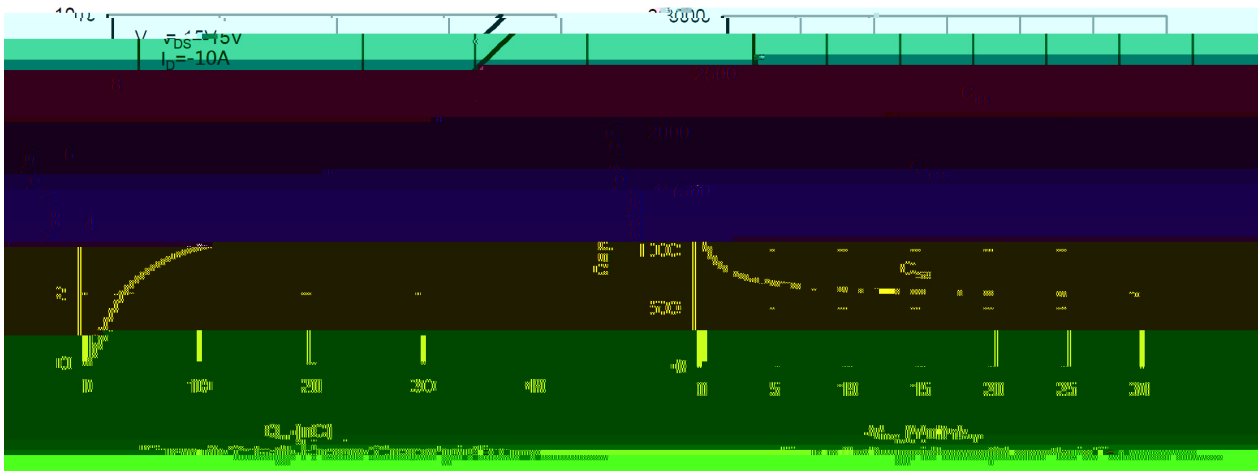


Figure 10: Normalized Maximum Transient Thermal Impedance



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<sup>a</sup> ϕ y

1o• Ä ½ “ † 150 ½180 - k ž • 60 ½90sec;

2o• Q › “ † 245 r5 - k ž • 4 Ò 5 r0.5sec;

3o•D N ò i Ò 0 , † 2 ½10 - /sec.

Note:

1.Preheating:150~180 - , Time:60~90sec.

2.Peak Temp.:245 r5 - , Duration:5 r0.5sec.

3. Cooling Speed: 2~10 - /sec.

ÂD /Cã p ~ » ] / Resistance to Soldering Heat Test Conditions

“ † y 260 r5 -

ž • y 10 r1 sec.

Temp.:260±5

Time:10±1 sec

G P á / Packaging SPEC.

2 & x / REEL

| Package Type | Units ;>û !H | Dimension ;>û p . (unit Åmm <sup>3</sup> ) |
|--------------|--------------|--|
| 7>û ~ E      |              |  |